

## Problem 1

Cascode amplifier, so gain is

$$A_v = -\left(\frac{g_{m1}}{g_{o3}}\right) \cong -8000$$

## Problem 2

$$A_v = -\left(\frac{g_{m1}}{g_{o1}}\right) \frac{\beta}{2} \cong -400,000$$

## Problem 3

$$3 + A_v V_{in} = 3 + (1 * 10^{-6})(4 * 10^5) = 3.4V$$

This means it would be very difficult to get the system to be biased correctly.

## Problem 4

a) Due to the current source,  $V_{DrainQ} = V_{DD} - (10000 * I_{source})$ 

$$V_{DrainQ} = 1.8 - (10000 * 0.0001) = 0.8V$$

b)

The standard equation is  $-g_m R_D$ , but would be more appropriate to use  $-g_m Z_D$ . So,

$$Z_D = \left(10k\Omega \parallel \frac{Z_{C_L}}{10k\Omega + Z_{C_L}}\right)$$

$$Z_{C_L} = \frac{1}{sC}$$

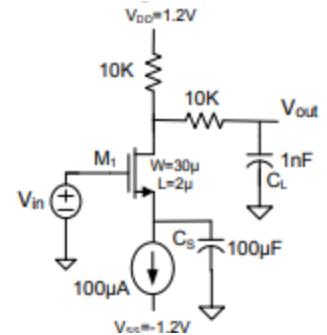
$$\frac{Z_{C_L}}{10k\Omega + Z_{C_L}} = \frac{\left(\frac{1}{sC}\right)}{10k\Omega + \left(\frac{1}{sC}\right)} = \frac{1}{1 + s * 10k\Omega * 1nF}$$

$$Z_D = \left(10k\Omega \parallel \frac{1}{1 + s * 10k\Omega * 1nF}\right) = \frac{1}{\frac{1}{10k\Omega} + s * 10k\Omega * 1nF}$$

$$Z_D = \frac{1}{\frac{1}{10k\Omega} + s * 10k\Omega * 1nF} = \frac{100000}{s + 10}$$

$$A_v = -g_m \left(\frac{100000}{s + 10}\right)$$

c)

 $-3dB$  bandwidth would be at 10 Hz

## Problem 5

The area of the resistor is  $2\mu * 30\mu = 60\mu^2$  at  $8566 \text{ aF}/\mu\text{m}^2$  is  $513.96 \text{ fF}$ .

This can be seen as in series with the  $10\text{k}\Omega$  resistor, on the other side of  $V_{out}$ , creating a basic  $RC$  filter with

$$-3\text{dB} = \frac{1}{2\pi RC} = \frac{1}{2\pi(10\text{k})(1.026\text{p})} = 3.09\text{M Hz}$$

## Problem 6

High			OR			A ~B			A		
A	B	Out	A	B	Out	A	B	Out	A	B	Out
1	1	1	1	1	1	1	1	1	1	1	1
1	0	1	1	0	1	1	0	1	1	0	1
0	1	1	0	1	1	0	1	0	0	1	0
0	0	1	0	0	0	0	0	1	0	0	0

~A B			B			(AB) (~A~B)			AND		
A	B	Out	A	B	Out	A	B	Out	A	B	Out
1	1	1	1	1	1	1	1	1	1	1	1
1	0	0	1	0	0	1	0	0	1	0	0
0	1	1	0	1	1	0	1	0	0	1	0
0	0	1	0	0	0	0	0	1	0	0	0

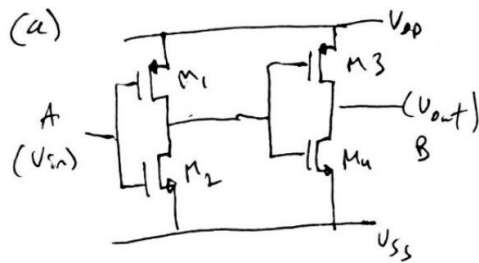
NAND			XOR			~B			A~B		
A	B	Out	A	B	Out	A	B	Out	A	B	Out
1	1	0	1	1	0	1	1	0	1	1	0
1	0	1	1	0	1	1	0	1	1	0	1
0	1	1	0	1	1	0	1	0	0	1	0
0	0	1	0	0	0	0	0	1	0	0	0

~A			~AB			NOR			Low		
A	B	Out	A	B	Out	A	B	Out	A	B	Out
1	1	0	1	1	0	1	1	0	1	1	0
1	0	0	1	0	0	1	0	0	1	0	0
0	1	1	0	1	1	0	1	0	0	1	0
0	0	1	0	0	0	0	0	1	0	0	0

The named ones are the most commonly used

Problem 7



Problem 8

Assume  $C_1$  is large, and set  $V_{DD} = 10V$

$$I_C = \frac{V_{DD} - V_{outQ}}{R_L} = \beta_n I_B = 100 * \frac{V_{DD} - 0.6V}{R_B}$$

$$\frac{10V - 5V}{2k\Omega} = 100 * \frac{10V - 0.6V}{R_B}$$

$$R_B = 940 k\Omega$$

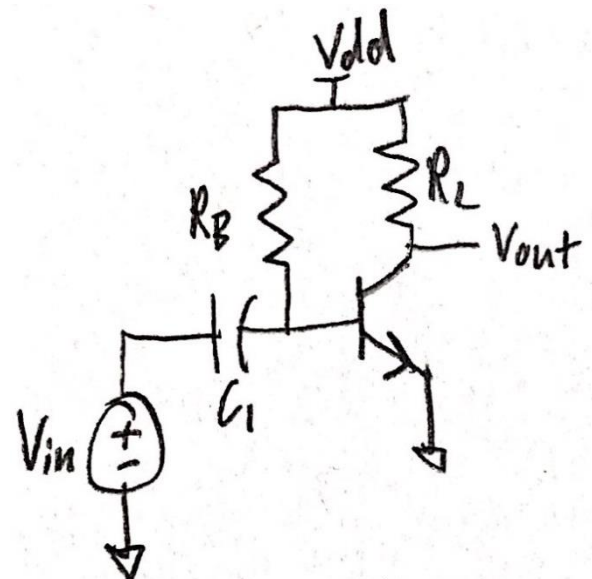
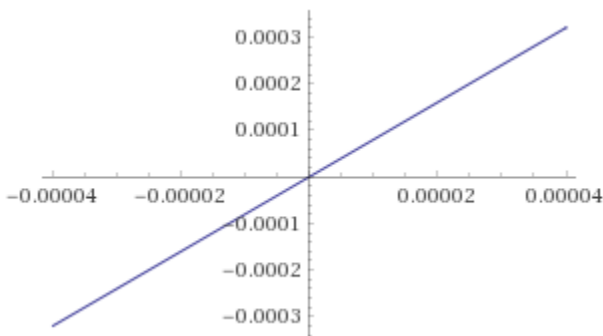
Image of design is on the right.

Problem 9

a)

$$I_{out} = \frac{A_{E1}}{A_{E0}} (I_{in} + I_{BS}) - I_{BO} = 8I_{BS} + 320 - 320 = 8I_{in}$$

b) I used WolframAlpha

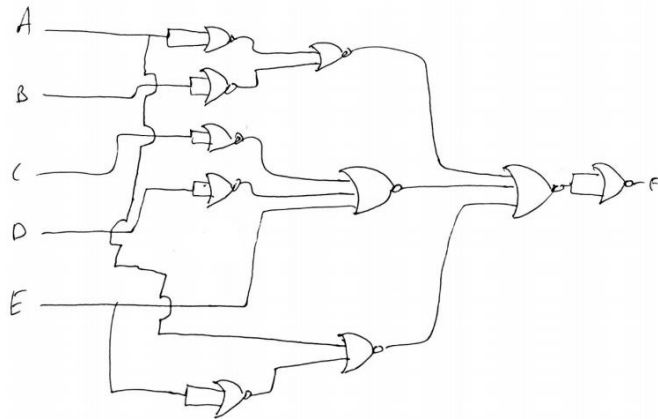


Problem 10

a.)  $F = AB + CD\bar{E} + \bar{A}E$

b.) Assign  $F = (A \& B) \mid (C \& D \& \sim E) \mid (\sim A \& E)$

c.)  $F = \overline{\overline{A}\overline{B} + \overline{C} + \overline{D} + E + A + \overline{E}}$



e.) Just replace all NOR gates in above schematic with transistor level NOR gate

Problem 11

$$F = AB + \bar{C}\bar{B}$$

